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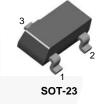
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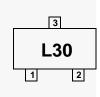
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BAV23S — Small Signal Diode



BAV23S Small Signal Diode





Connection Diagram



Ordering Information

| Part Number | Top Mark | Package | Packing Method | |
|-------------|----------|-----------|----------------|--|
| BAV23S | L30 | SOT-23 3L | Tape and Reel | |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

| Symbol | Parameter | | Value | Unit |
|--------------------|--|-------------------------------|-------------|------|
| V _{RRM} | Maximum Repetitive Reverse Voltage | | 250 | V |
| I _{F(AV)} | Average Rectified Forward Current | | 200 | mA |
| | Non-Repetitive Peak Forward Surge Current | Pulse Width = 1.0 microsecond | 9.0 | A |
| IFSM | | Pulse Width = 100 microsecond | 3.0 | |
| T _{STG} | Storage Temperature Range | | -55 to +150 | °C |
| TJ | Operating Junction Temperature | | 150 | °C |

Thermal Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

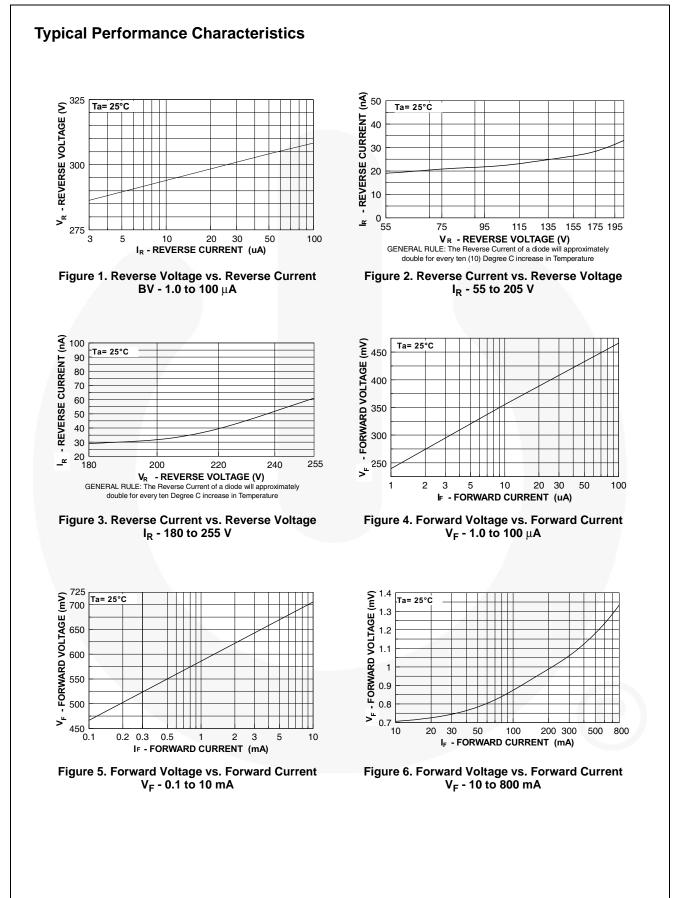
| Symbol | Parameter | Max. | Unit |
|-----------------------|---|------|------|
| PD | Power Dissipation | 350 | mW |
| $R_{	extsf{	heta}JA}$ | Thermal Resistance, Junction-to-Ambient | 357 | °C/W |

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Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

| Symbol | Parameter | Conditions | Min. | Max. | Unit |
|-----------------|-----------------------|---|------|------|------|
| B _V | Breakdown Voltage | I _R = 100 μA | 250 | | V |
| V _F | Forward Voltage | I _F = 100 mA | | 1.0 | V |
| | | I _F = 200 mA | | 1.25 | V |
| I _R | Reverse Leakage | V _R = 250 V | | 100 | nA |
| | | V _R = 250 V, T _A = 150°C | | 100 | μA |
| t _{rr} | Reverse Recovery Time | $I_{\text{F}} = I_{\text{R}} = 30 \text{ mA}, I_{\text{RR}} = 3.0 \text{ mA}, \\ R_{\text{L}} = 100 \ \Omega$ | | 50 | ns |

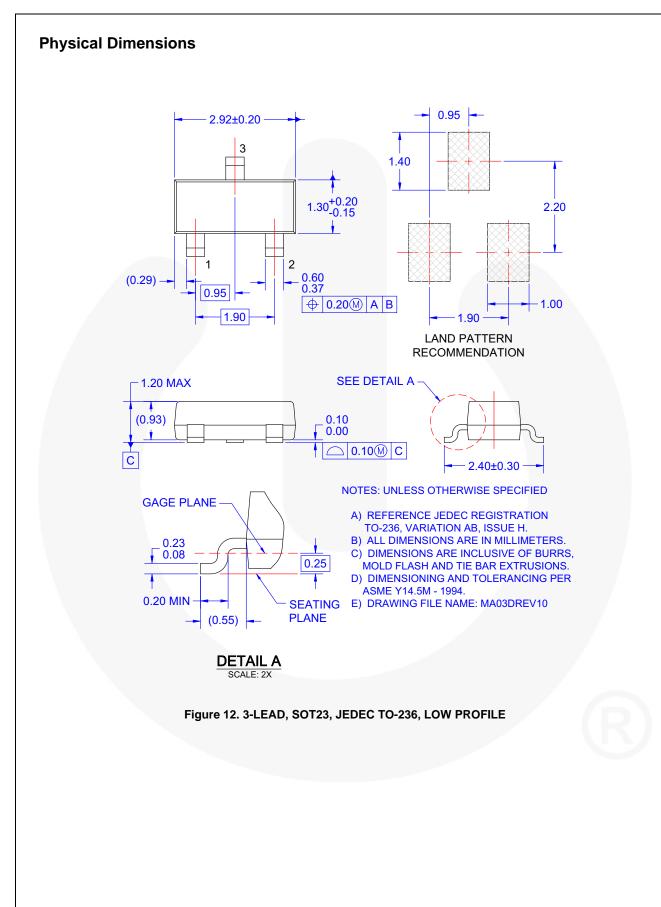


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Typical Performance Characteristics (Continued) 1.3 V_F - FORWARD VOLTAGE (mV) Ta= 25°C 800 <u>ال</u> 1.2 Та **CAPACITANCE** (F 0.9 600 Та <u>°C</u> 400 Ta= 200 0.8 L 0 2 4 6 8 10 12 14 15 0.001 0.003 0.01 0.03 0.1 0.3 3 10 **REVERSE VOLTAGE (V)** IF - FORWARD CURRENT (mA) Figure 7. Forward Voltage vs. Ambient Temperature Figure 8. Capacitance vs. Reverse Voltage V_F - 1.0 μA - 10 mA (- 40 to +80°C) 300 400 P - POWER DISSIPATION (mW) 250 300 F - CURRENT (mA) 200 200 150 100 100 50 °ò 50 100 150 0 25 50 75 100 125 150 25 75 125 T_A - AMBIENT TEMPERATURE (°C) T_A - AMBIENT TEMPERATURE (°C) Figure 10. Average Rectified Current(I_O) vs. Ambient Figure 9. Power Derating Curve Temperature(T_A) 50 REVERSE RECOVERY (nS) 00 01 01 02 IF = IR = 30 mA 100 Ohm Rioop 20 1.5 2 2.5 3 1 Irr - REVERSE RECOVERY CURRENT (mA) Figure 11. Reverse Recovery Time vs. **Reverse Recovery Current (Irr)**

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